

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







Automotive Current Mode PWM Control Circuit

The CS2841B provides all the necessary features to implement off-line fixed frequency current-mode control with a minimum number of external components.

The CS2841B (a variation of the CS2843A) is designed specifically for use in automotive operation. The low start threshold voltage of 8.0 V (typ), and the ability to survive 40 V automotive load dump transients are important for automotive subsystem designs. The CS2841 series has a history of quality and reliability in automotive applications.

The CS2841B incorporates a precision temperature-controlled oscillator with an internally trimmed discharge current to minimize variations in frequency. Duty-cycles greater than 50% are also possible. On board logic ensures that V_{REF} is stabilized before the output stage is enabled. Ion implant resistors provide tighter control of undervoltage lockout.

Features

- Optimized for Off-Line Control
- Internally Trimmed Temperature Compensated Oscillator
- Maximum Duty-Cycle Clamp
- V_{REF} Stabilized Before Output Stage Enabled
- Low Start-Up Current
- Pulse-By-Pulse Current Limiting
- Improved Undervoltage Lockout
- Double Pulse Suppression
- 1.0 % Trimmed Bandgap Reference
- High Current Totem Pole Output
- Pb-Free Packages are Available*



ON Semiconductor®

http://onsemi.com

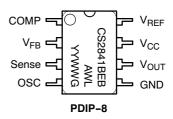


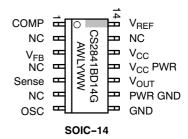
PDIP-8 N SUFFIX CASE 626



SOIC-14 D SUFFIX CASE 751A

PIN CONNECTIONS AND MARKING DIAGRAM





CS2841B = Device Code A = Assembly Location

WL = Wafer Lot
 YY, Y = Year
 WW = Work Week
 G = Pb-Free Package

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

ORDERING INFORMATION

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

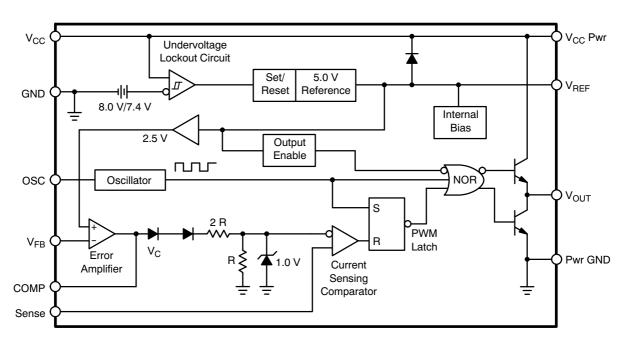


Figure 1. Block Diagram

MAXIMUM RATINGS

Rating	Value	Unit	
Supply Voltage (Low Impedance Source)		40	V
Output Current		±1.0	Α
Output Energy (Capacitive Load)		5.0	μЈ
Analog Inputs (V _{FB} , Sense)		-0.3 to 5.5	٧
Error Amp Output Sink Current		10	mA
·	Wave Solder (through hole styles only) Note 1 Reflow (SMD styles only) Note 2	260 peak 230 peak	ο̈́ο

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. 10 seconds max
- 2. 60 seconds max above 183°C

ORDERING INFORMATION

Device	Package	Shipping [†]
CS2841BEBN8	PDIP-8	50 Units / Rail
CS2841BEBN8G	PDIP-8 (Pb-Free)	50 Units / Rail
CS2841BED14	SOIC-14	55 Units / Rail
CS2841BED14G	SOIC-14 (Pb-Free)	55 Units / Rail
CS2841BEDR14	SOIC-14	2500 / Tape & Reel
CS2841BEDR14G	SOIC-14 (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

 $\textbf{ELECTRICAL CHARACTERISTICS} \ (-40^{\circ}C \leq T_{A} \leq 85^{\circ}C, \ R_{T} = 680 \ k\Omega, \ C_{T} = 0.022 \ \mu\text{F for Triangular Mode, V}_{CC} = 15 \ V \ (\text{Note 3}), \ R_{T} = 680 \ k\Omega, \ R_{T}$ R_T = 10 k Ω , C_T = 3.3 nF for Sawtooth Mode (see Figure 7); unless otherwise specified.)

Characteristic	Test Conditions	Min	Тур	Max	Unit
Reference Section	·	•	•	•	•
Output Voltage	age $T_J = 25^{\circ}\text{C}, I_{OUT} = 1.0 \text{ mA}$		5.0	5.1	٧
Line Regulation	8.4 ≤ V _{CC} ≤ 16 V	-	6.0	20	mV
Load Regulation	1.0 ≤ I _{OUT} ≤ 20 mA	-	6.0	25	mV
Temperature Stability	Note 4	-	0.2	0.4	mV/°C
Total Output Variation	Line, Load, Temp. Note 4	4.82	-	5.18	V
Output Noise Voltage	10 Hz ≤ f ≤ 10 kHz, T _J = 25°C. Note 4	-	50	-	μV
Long Term Stability	T _A = 125°C, 1000 Hrs. Note 4	-	5.0	25	mV
Output Short Circuit	T _A = 25°C	-30	-100	-180	mA
Oscillator Section		1	1	1	
Initial Accuracy	Sawtooth Mode: $T_J = 25^{\circ}C$. See Figure 7. Sawtooth Mode: $-40^{\circ}C \le T_A \le +85^{\circ}C$ Triangular Mode: $T_J = 25^{\circ}C$. See Figure 7.	47 44 44	52 52 52	57 60 60	kHz kHz kHz
Voltage Stability	8.4 ≤ V _{CC} ≤ 16 V	-	0.2	1.0	%
Temperature Stability	Sawtooth Mode: $T_{MIN} \le T_A \le T_{MAX}$. Note 4 Triangular Mode: $T_{MIN} \le T_A \le T_{MAX}$. Note 4		5.0 8.0		% %
Amplitude	V _{OSC} (Peak to Peak)	-	1.7	-	V
Discharge Current	$T_{J} = 25^{\circ}C$ $T_{MIN} \le T_{A} \le T_{MAX}$	7.4 7.2	8.3	9.2 9.4	mA mA
Error Amp Section					
Input Voltage	V _{COMP} = 2.5 V	2.42	2.5	2.58	V
Input Bias Current	V _{FB} = 0 V	-	-0.3	-2.0	μΑ
A _{VOL}	2.0 ≤ V _{OUT} ≤ 4.0 V	65	90	-	dB
Unity Gain Bandwidth	Note 4	0.7	1.0	-	MHz
PSRR	8.4 V ≤ V _{CC} ≤ 16 V	60	70	-	dB
Output Sink Current	V _{FB} = 2.7 V, V _{COMP} = 1.1 V	2.0	6.0	-	mA
Output Source Current	V _{FB} = 2.3 V, V _{COMP} = 5.0 V	-0.5	-0.8	-	mA
V _{OUT} High	V_{FB} = 2.3 V, R_L = 15 k Ω to Ground	5.0	6.0	-	V
V _{OUT} Low	V_{FB} = 2.7 V, R_L = 15 k Ω to V_{REF}	-	0.7	1.1	V
Current Sense Section					
Gain	Notes 5 and 6	2.85	3.0	3.15	V/V
Maximum Input Signal	V _{COMP} = 5.0 V. Note 5	0.9	1.0	1.1	V
PSRR	12 V ≤ V _{CC} ≤ 25 V. Note 5	-	70	-	dB
Input Bias Current	V _{Sense} = 0 V	-	-2.0	-10	μΑ
Delay to Output	T _J = 25°C. Note 4	-	150	300	ns
	•		*	•	-

$$A = \frac{\Delta V_{\mbox{COMP}}}{\Delta V_{\mbox{Sense}}}; \ 0 \le V_{\mbox{Sense}} \le 0.8 \ V.$$

^{3.} Adjust V_{CC} above the start threshold before setting at 15 V
4. These parameters, although guaranteed, are not 100% tested in production
5. Parameter measured at trip point of latch with V_{FB} = 0
6. Gain defined as:

ELECTRICAL CHARACTERISTICS ($-40^{\circ}C \le T_A \le 85^{\circ}C$, $R_T = 680 \text{ k}\Omega$, $C_T = 0.022 \text{ }\mu\text{F}$ for Triangular Mode, $V_{CC} = 15 \text{ V}$ (Note 3), $R_T = 10 \text{ k}\Omega$, $C_T = 3.3 \text{ nF}$ for Sawtooth Mode (see Figure 7); unless otherwise specified.)

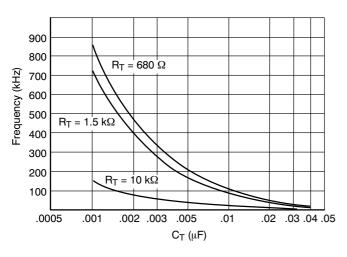
Characteristic	Test Conditions	Min	Тур	Max	Unit
Output Section		•	•	•	•
Output Low Level	I _{SINK} = 20 mA I _{SINK} = 200 mA	-	0.1 1.5	0.4 2.2	V V
Output High Level I _{SOURCE} = 20 mA I _{SOURCE} = 200 mA		13 12	13.5 13.5		V V
Rise Time $T_J = 25$ °C, $C_L = 1.0$ nF. Note 7		-	50	150	ns
Fall Time	T _J = 25°C, C _L = 1.0 nF. Note 7	-	50	150	ns
Output Leakage	Undervoltage Active, V _{OUT} = 0	-	-0.01	-10	μΑ
Total Standby Current					
Startup Current	-	-	0.5	1.0	mA
Operating Supply Current I _{CC} $V_{FB} = V_{Sense} = 0 \text{ V}, R_T = 10 \text{ k}\Omega, C_T = 3.3 \text{ nF}$		-	11	17	mA
Undervoltage Lockout Section			•	•	•
Start Threshold	-	7.6	8.0	8.4	V
Min. Operating Voltage	After Turn On	7.0	7.4	7.8	V
	L.	1		1	

^{7.} These parameters, although guaranteed, are not 100% tested in production.

PACKAGE PIN DESCRIPTION

PACKAGE PIN #					
PDIP-8	SOIC-14	PIN SYMBOL	FUNCTION		
1	1	COMP	Error Amp Output, Used to Compensate Error Amplifier		
2	3	V _{FB}	Error Amp Inverting Input		
3	5	Sense	Noninverting Input to Current Sense Comparator		
4	7	osc	Oscillator Timing Network with Capacitor to Ground, Resistor to V _{REF}		
5	8	GND	Ground		
	9	Pwr GND	Output Driver Ground		
6	10	V _{OUT}	Output Drive Pin		
	11	V _{CC} Pwr	Output Driver Positive Supply		
7	12	V _{CC}	Positive Power Supply		
8	14	V _{REF}	Output of 5.0 V Internal Reference		
	2, 4, 6, 13	NC	No Connection		

TYPICAL PERFORMANCE CHARACTERISTICS



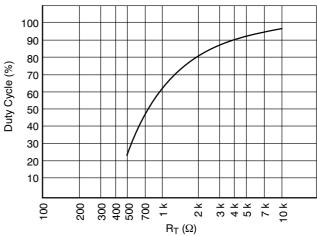


Figure 2. Oscillator Frequency vs. C_T

Figure 3. Oscillator Duty Cycle vs. R_T

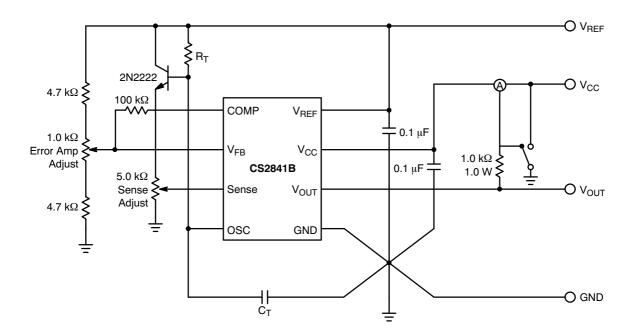


Figure 4. Test Circuit

CIRCUIT DESCRIPTION

Undervoltage Lockout

During Undervoltage Lockout (Figure 5), the output driver is biased to a high impedance state. The output should be shunted to ground with a resistor to prevent output leakage current from activating the power switch.

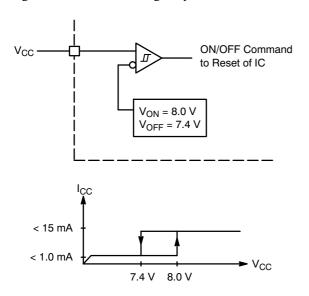


Figure 5. Typical Undervoltage Characteristics

PWM Waveform

To generate the PWM waveform, the control voltage from the error amplifier is compared to a current sense signal representing the peak output inductor current (Figure 6). An increase in V_{CC} causes the inductor current slope to increase, thus reducing the duty cycle. This is an inherent feed-forward characteristic of current mode control, since the control voltage does not have to change during changes of input supply voltage.

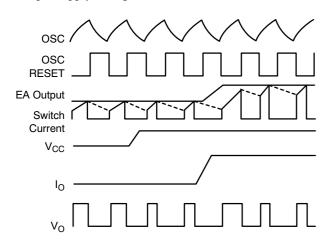
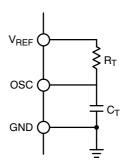
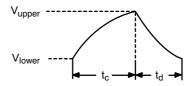


Figure 6. Timing Diagram for Key CS2841B Parameters

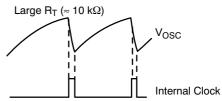
When the power supply sees a sudden large output current increase, the control voltage will increase allowing the duty cycle to momentarily increase. Since the duty cycle tends to exceed the maximum allowed to prevent transformer saturation in some power supplies, the internal oscillator waveform provides the maximum duty cycle clamp as programmed by the selection of OSC components.



Timing Parameters



Sawtooth Mode



Triangular Mode

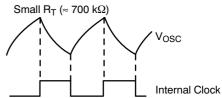


Figure 7. Oscillator Timing Network and Parameters

Setting the Oscillator

Oscillator timing capacitor, C_T , is charged by V_{REF} through R_T and discharged by an internal current source. During the discharge time, the internal clock signal blanks out the output to the Low state, thus providing a user selected maximum duty cycle clamp. Charge and discharge times are determined by the general formulas:

$$t_{C} = R_{T}C_{T} ln \left(\frac{V_{REF} - V_{lower}}{V_{REF} - V_{upper}} \right)$$

$$t_{d} = R_{T}C_{T}In \left(\frac{V_{REF} - I_{d}R_{T} - V_{upper}}{V_{REF} - I_{d}R_{T} - V_{lower}} \right)$$

Substituting in typical values for the parameters in the above formulas:

$$\begin{array}{l} \text{VREF} = 5.0 \text{ V} \\ \text{Vupper} = 2.7 \text{ V} \\ \text{Vlower} = 1.0 \text{ V} \\ \text{I}_{d} = 8.3 \text{ mA} \\ \text{t}_{C} \approx 0.5534 \text{RTCT} \end{array}$$

$$t_d = R_T C_T \ln \left(\frac{2.3 - 0.0083 R_T}{4.0 - 0.0083 R_T} \right)$$

The frequency and maximum duty cycle can be determined from the Typical Performance Characteristic graphs.

Grounding

High peak currents associated with capacitive loads necessitate careful grounding techniques. Timing and bypass capacitors should be connected close to GND pin in a single point ground.

The transistor and 5.0 k Ω potentiometer are used to sample the oscillator waveform and apply an adjustable ramp to Sense.

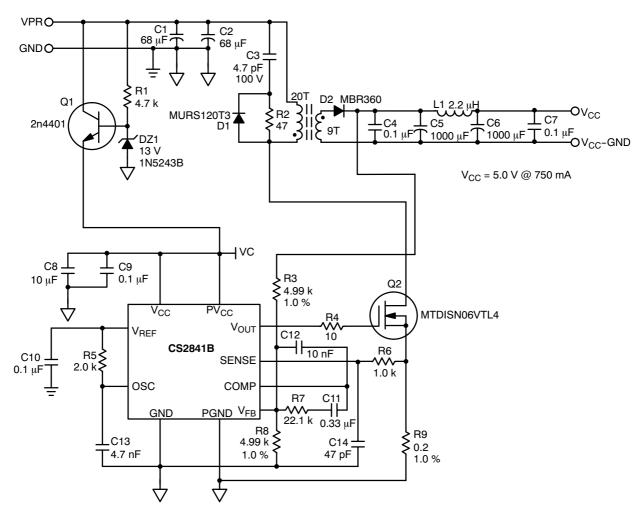


Figure 8. Flyback Application

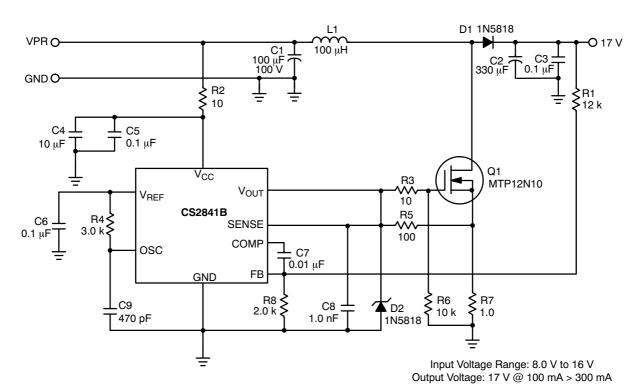


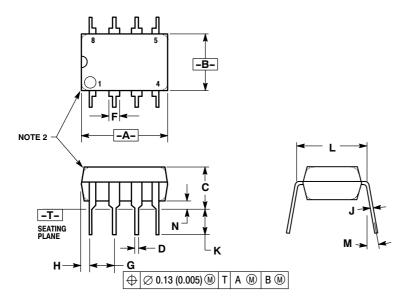
Figure 9. Boost Application

PACKAGE THERMAL DATA

Parame	eter	PDIP-8	SOIC-14	Unit
$R_{ heta JC}$	Typical	52	30	°C/W
$R_{\theta JA}$	Typical	100	125	°C/W

PACKAGE DIMENSIONS

PDIP-8 CASE 626-05 ISSUE L

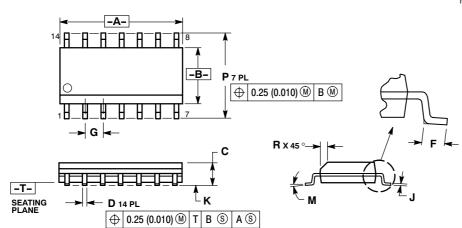


- NOTES:
 1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
 2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
 3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.40	10.16	0.370	0.400
В	6.10	6.60	0.240	0.260
С	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54	BSC	0.100 BSC	
Н	0.76	1.27	0.030 0.05	
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300	BSC
М		10°		10°
N	0.76	1.01	0.030	0.040

PACKAGE DIMENSIONS

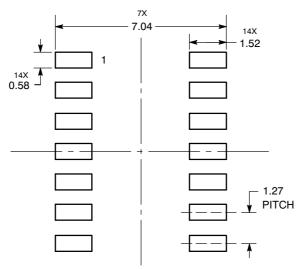
SOIC-14 CASE 751A-03 **ISSUE J**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE
 MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	8.55	8.75	0.337	0.344
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
М	0 °	7°	0 °	7°
Р	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

SOLDERING FOOTPRINT



DIMENSIONS: MILLIMETERS

ON Semiconductor and un are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice on semiconductor and are registered raderians of semiconductor Components industries, Ite (SciLLC) solic (SciLC). Solic the serves are right to make changes without further holice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center

Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative